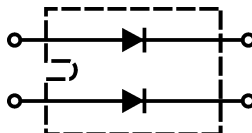


# Fast Recovery Epitaxial Diode (FRED)

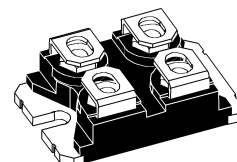
**DSEI 2x 61**

**$I_{FAVM} = 2 \times 52 \text{ A}$**   
 **$V_{RRM} = 1200 \text{ V}$**   
 **$t_{rr} = 40 \text{ ns}$**

| $V_{RSM}$<br>V | $V_{RRM}$<br>V | Type           |
|----------------|----------------|----------------|
| 1200           | 1200           | DSEI 2x 61-12B |



miniBLOC, SOT-227 B  
 E72873



| Symbol                                  | Test Conditions                                                                                                                                   | Maximum Ratings (per diode) |                                              |
|-----------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------|----------------------------------------------|
| $I_{FRMS}$<br>$I_{FAVM}$ ①<br>$I_{FRM}$ | $T_{VJ} = T_{VJM}$<br>$T_C = 50^\circ\text{C}$ ; rectangular, $d = 0.5$<br>$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$ | 100<br>52<br>700            | A<br>A<br>A                                  |
| $I_{FSM}$                               | $T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine<br>$t = 8.3 \text{ ms}$ (60 Hz), sine                                             | 450<br>500                  | A<br>A                                       |
|                                         | $T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine<br>$t = 8.3 \text{ ms}$ (60 Hz), sine                                            | 400<br>440                  | A<br>A                                       |
| $I^2t$                                  | $T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine<br>$t = 8.3 \text{ ms}$ (60 Hz), sine                                               | 1000<br>1050                | $\text{A}^2\text{s}$<br>$\text{A}^2\text{s}$ |
|                                         | $T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine<br>$t = 8.3 \text{ ms}$ (60 Hz), sine                                            | 800<br>810                  | $\text{A}^2\text{s}$<br>$\text{A}^2\text{s}$ |
| $T_{VJ}$                                |                                                                                                                                                   | -40...+150                  | $^\circ\text{C}$                             |
| $T_{VJM}$                               |                                                                                                                                                   | 150                         | $^\circ\text{C}$                             |
| $T_{stg}$                               |                                                                                                                                                   | -40...+150                  | $^\circ\text{C}$                             |
| $P_{tot}$                               | $T_C = 25^\circ\text{C}$                                                                                                                          | 180                         | W                                            |
| $V_{ISOL}$                              | 50/60 Hz, RMS<br>$I_{ISOL} \leq 1 \text{ mA}$                                                                                                     | 2500                        | V~                                           |
| $M_d$                                   | Mounting torque<br>Terminal connection torque (M4)                                                                                                | 1.5/13<br>1.5/13            | Nm/lb.in.<br>Nm/lb.in.                       |
| Weight                                  |                                                                                                                                                   | 30                          | g                                            |

| Symbol     | Test Conditions                                                                                                                                                | Characteristic Values (per diode) |                                    |
|------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------|------------------------------------|
|            |                                                                                                                                                                | typ.                              | max.                               |
| $I_R$      | $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$<br>$T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$<br>$T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$ |                                   | 2.2<br>0.5<br>14<br>mA<br>mA<br>mA |
| $V_F$      | $I_F = 60 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$<br>$T_{VJ} = 25^\circ\text{C}$                                                                             |                                   | 2.15<br>2.50<br>V<br>V             |
| $V_{T0}$   | For power-loss calculations only                                                                                                                               |                                   | 1.65<br>V                          |
| $r_T$      | $T_{VJ} = T_{VJM}$                                                                                                                                             |                                   | 8.3<br>$\text{m}\Omega$            |
| $R_{thJC}$ |                                                                                                                                                                | 0.7                               | K/W                                |
| $R_{thCK}$ |                                                                                                                                                                | 0.05                              | K/W                                |
| $t_{rr}$   | $I_F = 1 \text{ A}$ ; $-di/dt = 200 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$                                                | 40                                | 60<br>ns                           |
| $I_{RM}$   | $V_R = 540 \text{ V}$ ; $I_F = 60 \text{ A}$ ; $-di_F/dt = 480 \text{ A}/\mu\text{s}$<br>$L \leq 0.05 \mu\text{H}$ ; $T_{VJ} = 100^\circ\text{C}$              | 32                                | 36<br>A                            |

## Features

- International standard package miniBLOC (ISOTOP compatible)
- Isolation voltage 2500 V~
- 2 independent FRED in 1 package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour

## Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

①  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ ,  $V_R = 0.8 V_{RRM}$ , duty cycle  $d = 0.5$

Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions

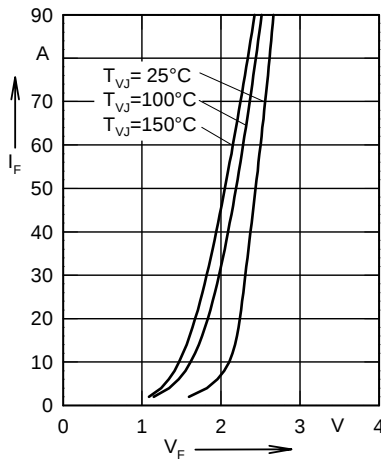


Fig. 1 Forward current versus voltage drop.

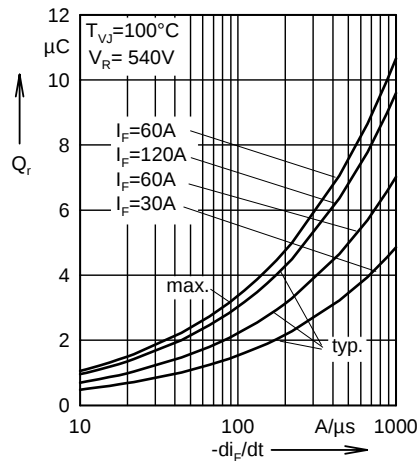


Fig. 2 Recovery charge versus  $-di_F/dt$ .

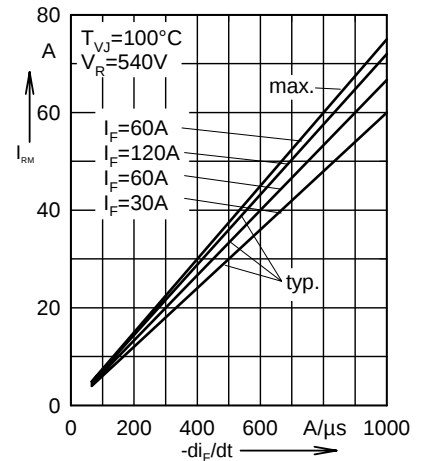


Fig. 3 Peak reverse current versus  $-di_F/dt$ .

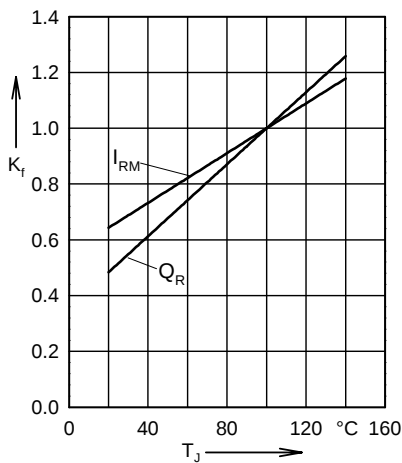


Fig. 4 Dynamic parameters versus junction temperature.

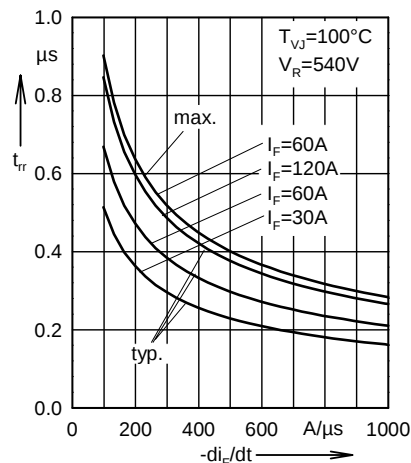


Fig. 5 Recovery time versus  $-di_F/dt$ .

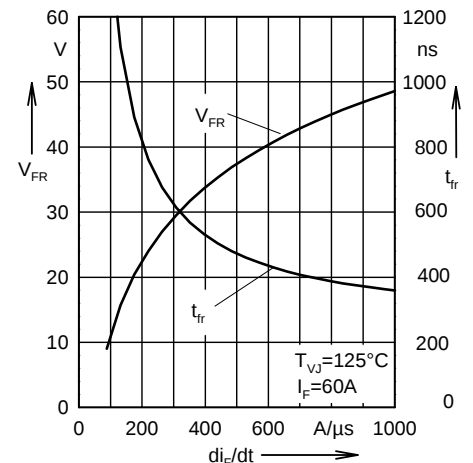


Fig. 6 Peak forward voltage versus  $di_F/dt$ .

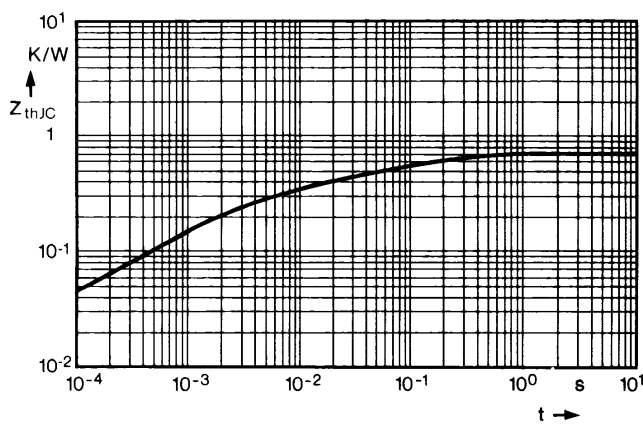
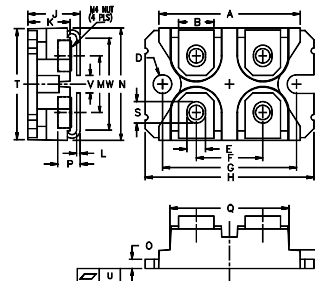


Fig. 7 Transient thermal impedance junction to case.

### Dimensions



miniBLOC SOT-227 B  
M4 screws (4x) supplied

| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 31.50      | 31.88 | 1.240  | 1.255 |
| B    | 7.80       | 8.20  | 0.307  | 0.323 |
| C    | 4.09       | 4.29  | 0.161  | 0.169 |
| D    | 4.09       | 4.29  | 0.161  | 0.169 |
| E    | 4.09       | 4.29  | 0.161  | 0.169 |
| F    | 14.91      | 15.11 | 0.587  | 0.595 |
| G    | 30.12      | 30.30 | 1.186  | 1.193 |
| H    | 37.80      | 38.20 | 1.489  | 1.505 |
| J    | 11.68      | 12.22 | 0.460  | 0.481 |
| K    | 8.92       | 9.60  | 0.351  | 0.378 |
| L    | 0.76       | 0.84  | 0.030  | 0.033 |
| M    | 12.60      | 12.85 | 0.496  | 0.506 |
| N    | 25.15      | 25.42 | 0.990  | 1.001 |
| O    | 1.98       | 2.13  | 0.078  | 0.084 |
| P    | 4.95       | 5.97  | 0.195  | 0.235 |
| Q    | 26.54      | 26.90 | 1.045  | 1.059 |
| R    | 3.94       | 4.42  | 0.155  | 0.174 |
| S    | 4.72       | 4.85  | 0.186  | 0.191 |
| T    | 24.59      | 25.07 | 0.968  | 0.987 |
| U    | -0.05      | 0.1   | -0.002 | 0.004 |
| V    | 3.30       | 4.57  | 0.130  | 0.180 |
| W    | 0.780      | 0.830 | 0.031  | 0.033 |